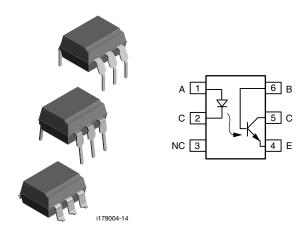


www.vishay.com

## Vishay Semiconductors

# Optocoupler, Phototransistor Output, with Base Connection



#### **DESCRIPTION**

The CNY17 is an optically coupled pair consisting of a gallium arsenide infrared emitting diode optically coupled to a silicon NPN phototransitor.

Signal information, including a DC level, can be transmitted by the device while maintaining a high degree of electrical isolation between input and output.

The CNY17 can be used to replace relays and transformers in many digital interface applications, as well as analog applications such as CRT modulation.

#### **FEATURES**

- Isolation test voltage: 5000 V<sub>RMS</sub>
- Long term stability
- Industry standard dual-in-line package
- Material categorization:
   For definitions of compliance please see
   www.vishay.com/doc?99912





ROHS

### **AGENCY APPROVALS**

- Underwriters lab file no. E52744
- cUL tested to CSA 22.2 bulletin 5A
- DIN EN 60747-5-5 (VDE 0884-5)
- BSI IEC 60950, IEC 60065
- FIMKO
- CQC

ORDERING INFORMATION					
C N Y 1 7 - PART NUMBER	# CTR BIN	X 0 # # PACKAGE OPTION	TAPE AND REEL	DIP-6  7.62 mm  Option 7	Option 6  10.16 mm  Option 9

AGENCY CERTIFIED/PACKAGE	CTR (%)					
UL, cUL, BSI, FIMKO	40 to 80	63 to 125	100 to 200	160 to 320		
DIP-6	CNY17-1	CNY17-2	CNY17-3	CNY17-4		
DIP-6, 400 mil, option 6	CNY17-1X006	CNY17-2X006	CNY17-3X006	CNY17-4X006		
SMD-6, option 7	CNY17-1X007T (1)	CNY17-2X007T (1)	CNY17-3X007T (1)	CNY17-4X007T (1)		
SMD-6, option 9	CNY17-1X009T (1)	CNY17-2X009T (1)	CNY17-3X009T (1)	CNY17-4X009T (1)		
VDE, UL, CUL, BSI, FIMKO	40 to 80	63 to 125	100 to 200	160 to 320		
DIP-6	CNY17-1X001	CNY17-2X001	CNY17-3X001	CNY17-4X001		
DIP-6, 400 mil, option 6	CNY17-1X016	CNY17-2X016	CNY17-3X016	CNY17-4X016		
SMD-64, option 7	CNY17-1X017	CNY17-2X017T (1)	CNY17-3X017T (1)	CNY17-4X017T (1)		
SMD-6, option 9	-	CNY17-2X019T (1)	-	-		

#### Note

 $^{(1)}$  Also available in tubes, do not put T on the end.



ABSOLUTE MAXIMUM RATINGS (T <sub>amb</sub> = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT			
INPUT							
Reverse voltage		$V_R$	6	V			
Forward current		I <sub>F</sub>	60	mA			
Forward surge current	t <sub>p</sub> ≤ 10 μs	I <sub>FSM</sub>	2.5	А			
LED power dissipation	at 25 °C	P <sub>diss</sub>	70	mW			
OUTPUT							
Collector emitter breakdown voltage		BV <sub>CEO</sub>	70	V			
Emitter base breakdown voltage		BV <sub>EBO</sub>	7	V			
Collector current		I <sub>C</sub>	50	mA			
Collector current	$t_p/T = 0.5, t_p \le 10 \text{ ms}$	I <sub>C</sub>	100	mA			
Power dissipation		P <sub>diss</sub>	150	mW			
COUPLER							
Isolation test voltage between emitter and detector	t = 1 s	V <sub>ISO</sub>	5000	$V_{RMS}$			
Creepage distance			≥ 7	mm			
Clearance distance			≥ 7	mm			
Isolation thickness between emitter and detector			≥ 0.4	mm			
Comparative tracking index per DIN IEC 112/VDE 0303, part 1			≥ 175				
Isolation resistance	V <sub>IO</sub> = 500 V, T <sub>amb</sub> = 25 °C	R <sub>IO</sub>	≥ 10 <sup>12</sup>	Ω			
isolation resistance	V <sub>IO</sub> = 500 V, T <sub>amb</sub> = 100 °C	R <sub>IO</sub>	≥ 10 <sup>11</sup>	Ω			
Storage temperature		T <sub>stg</sub>	- 55 to + 150	°C			
Operating temperature		T <sub>amb</sub>	- 55 to + 110	°C			
Soldering temperature (1)	2 mm from case, ≤ 10 s	T <sub>sld</sub>	260	°C			
Total power dissipation		P <sub>diss</sub>	220	mW			

#### Notes

- Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not
  implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute
  maximum ratings for extended periods of the time can adversely affect reliability.
- (1) Refer to reflow profile for soldering conditions for surface mounted devices (SMD). Refer to wave profile for soldering conditions for through hole devices (DIP).

<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)								
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT	
INPUT								
Forward voltage	I <sub>F</sub> = 60 mA		$V_{F}$		1.39	1.65	V	
Breakdown voltage	I <sub>R</sub> = 10 μA		$V_{BR}$	6			V	
Reverse current	V <sub>R</sub> = 6 V		I <sub>R</sub>		0.01	10	μΑ	
Capacitance	$V_R = 0 V, f = 1 MHz$		Co		25		pF	
Thermal resistance			R <sub>th</sub>		750		K/W	
OUTPUT		•						
Collector emitter capacitance	$V_{CE} = 5 \text{ V}, f = 1 \text{ MHz}$		C <sub>CE</sub>		5.2		pF	
Collector base capacitance	V <sub>CE</sub> = 5 V, f = 1 MHz		C <sub>CB</sub>		6.5		pF	
Emitter base capacitance	V <sub>CE</sub> = 5 V, f = 1 MHz		C <sub>EB</sub>		7.5		pF	
Thermal resistance			R <sub>th</sub>		500		K/W	
COUPLER		•						
Collector emitter, saturation voltage	$V_F = 10 \text{ mA}, I_C = 2.5 \text{ mA}$		V <sub>CEsat</sub>		0.25	0.4	V	
Coupling capacitance			C <sub>C</sub>		0.6		pF	
		CNY17-1	I <sub>CEO</sub>		2	50	nA	
Collector emitter leakers or	V 10 V	CNY17-2	I <sub>CEO</sub>		2	50	nA	
Collector emitter, leakage current	V <sub>CE</sub> = 10 V	CNY17-3	I <sub>CEO</sub>		5	100	nA	
		CNY17-4	I <sub>CEO</sub>		5	100	nA	

## Note

Minimum and maximum values were tested requierements. Typical values are characteristics of the device and are the result of engineering
evaluations. Typical values are for information only and are not part of the testing requirements.

CURRENT TRANSFER RATIO (T <sub>amb</sub> = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
I <sub>C</sub> /I <sub>F</sub>		CNY17-1	CTR	40		80	%
	$V_{CF} = 5 \text{ V}, I_{F} = 10 \text{ mA}$	CNY17-2	CTR	63		125	%
	VCE = 3 V, IF = 10 IIIA	CNY17-3	CTR	100		200	%
		CNY17-4	CTR	160		320	%
	V <sub>CF</sub> = 5 V, I <sub>F</sub> = 1 mA	CNY17-1	CTR	13	30		%
		CNY17-2	CTR	22	45		%
	VCE = 5 V, IF = 1 IIIA	CNY17-3	CTR	34	70		%
		CNY17-4	CTR	56	90		%

PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
LINEAR OPERATION	(without saturation)						
Turn-on time	$I_F = 10 \text{ mA}, V_{CC} = 5 \text{ V}, R_L = 75 \Omega$		t <sub>on</sub>		3		μs
Rise time	$I_F = 10 \text{ mA}, V_{CC} = 5 \text{ V}, R_L = 75 \Omega$		t <sub>r</sub>		2		μs
Turn-off time	$I_F = 10 \text{ mA}, V_{CC} = 5 \text{ V}, R_L = 75 \Omega$		t <sub>off</sub>		2.3		μs
Fall time	$I_F = 10 \text{ mA}, V_{CC} = 5 \text{ V}, R_L = 75 \Omega$		t <sub>f</sub>		2		μs
Cut-off frequency	$I_F = 10 \text{ mA}, V_{CC} = 5 \text{ V}, R_L = 75 \Omega$		f <sub>CO</sub>		110		kHz
<b>SWITCHING OPERAT</b>	ION (with saturation)						
	I <sub>F</sub> = 20 mA	CNY17-1	t <sub>on</sub>		3		μs
Turn-on time	I <sub>F</sub> = 10 mA	CNY17-2	t <sub>on</sub>		4.2		μs
rum-on time		CNY17-3	t <sub>on</sub>		4.2		μs
	I <sub>F</sub> = 5 mA	CNY17-4	t <sub>on</sub>		6		μs
	I <sub>F</sub> = 20 mA	CNY17-1	t <sub>r</sub>		2		μs
Rise time	I <sub>F</sub> = 10 mA	CNY17-2	t <sub>r</sub>		3		μs
nise time		CNY17-3	t <sub>r</sub>		3		μs
	$I_F = 5 \text{ mA}$	CNY17-4	t <sub>r</sub>		4.6		μs
	$I_F = 20 \text{ mA}$	CNY17-1	t <sub>off</sub>		18		μs
Turn-off time	I <sub>E</sub> = 10 mA	CNY17-2	t <sub>off</sub>		23		μs
Turn-on time	I <sub>F</sub> = 10 mA	CNY17-3	t <sub>off</sub>		23		μs
	$I_F = 5 \text{ mA}$	CNY17-4	t <sub>off</sub>		25		μs
	$I_F = 20 \text{ mA}$	CNY17-1	t <sub>f</sub>		11		μs
Fall time	I <sub>F</sub> = 10 mA	CNY17-2	t <sub>f</sub>		14		μs
ı alı tillic	$I_F = 10 \text{ mA}$	CNY17-3	t <sub>f</sub>		14		μs
	$I_F = 5 \text{ mA}$	CNY17-4	t <sub>f</sub>		15		μs

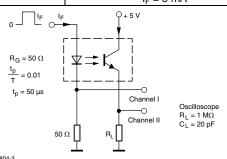


Fig. 1 - Test Circuit, Non-Saturated Operation

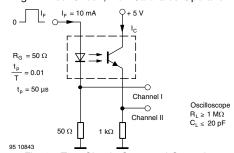


Fig. 2 - Test Circuit, Saturated Operation

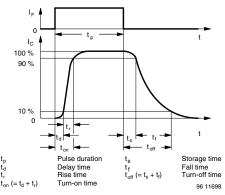


Fig. 3 - Switching Times



## TYPICAL CHARACTERISTICS (T<sub>amb</sub> = 25 °C, unless otherwise specified)

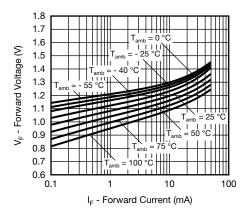


Fig. 4 - Forward Voltage vs. Forward Current

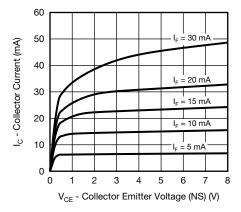


Fig. 5 - Collector Current vs. Collector Emitter Voltage (NS)

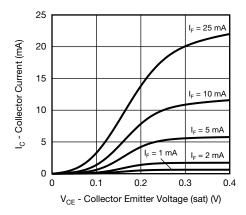


Fig. 6 - Collector Current vs. Collector Emitter Voltage (sat)

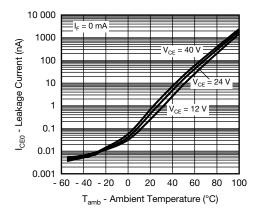


Fig. 7 - Leakage Current vs. Ambient Temperature

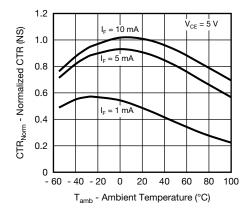


Fig. 8 - Normalized CTR (NS) vs. Ambient Temperature

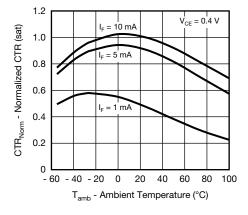


Fig. 9 - Normalized CTR (sat) vs. Ambient Temperature





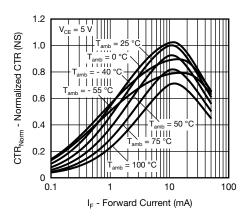


Fig. 10 - Normalized CTR (NS) vs. Forward Current

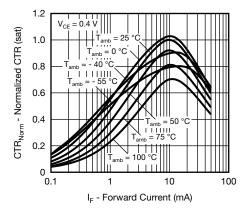


Fig. 11 - Normalized CTR (sat) vs. Forward Current

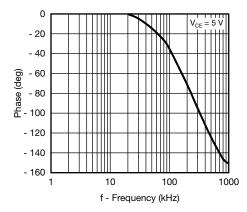


Fig. 12 - CTR Frequency vs. Phase Angle

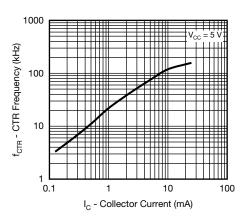


Fig. 13 - CTR Frequency vs. Collector Current

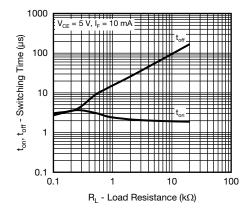
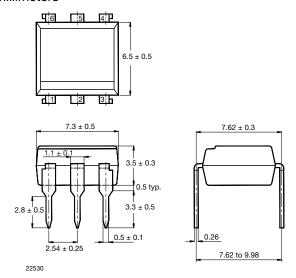
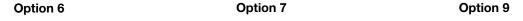


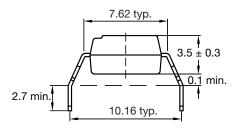
Fig. 14 - Switching Time vs. Load Resistance

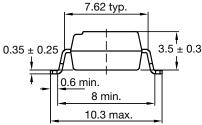


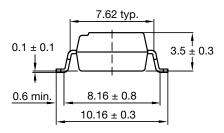
## **PACKAGE DIMENSIONS** in millimeters

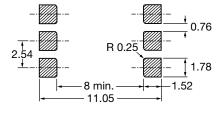


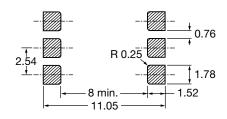












20802-34

### **PACKAGE MARKING**



### Notes

- VDE logo is only marked on option 1 parts. Option information is not marked on the part.
- Tape and reel suffix (T) is not part of the package marking.

## **TUBE AND TAPE INFORMATION**

DEVICES PER TUBE						
TYPE	UNITS/TUBE	TUBES/BOX	UNITS/BOX			
DIP-6	50	40	2000			

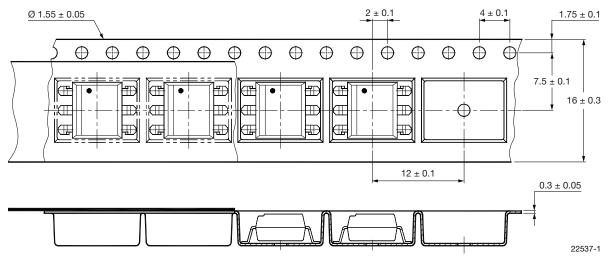


Fig. 15 - Tape and Reel Drawing, 1000 Units per Reel



## **Legal Disclaimer Notice**

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Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as RoHS-Compliant fulfill the definitions and restrictions defined under Directive 2011/65/EU of The European Parliament and of the Council of June 8, 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment (EEE) - recast, unless otherwise specified as non-compliant.

Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as Halogen-Free follow Halogen-Free requirements as per JEDEC JS709A standards. Please note that some Vishay documentation may still make reference to the IEC 61249-2-21 definition. We confirm that all the products identified as being compliant to IEC 61249-2-21 conform to JEDEC JS709A standards.

Revision: 02-Oct-12 Document Number: 91000